SO2907A

SMALL SIGNAL PNP TRANSISTOR

PRELIMINARY DATA

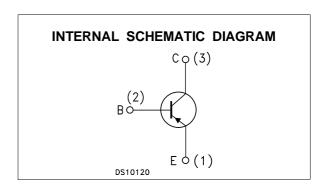
Туре	Marking		
SO2907A	P03		

- SILICON EPITAXIAL PLANAR PNP TRANSISTOR
- MINIATURE SOT-23 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- TAPE & REEL PACKING
- THE NPN COMPLEMENTARY TYPE IS SO2222A

APPLICATIONS

- WELL SUITABLE FOR PORTABLE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTOR WITH HIGH GAIN AND LOW SATURATION VOLTAGE





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Emitter Voltage (I _E = 0)	-60	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	-60	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)	-5	V
I _{CM}	Collector Peak Current	-0.8	А
P _{tot}	Total Dissipation at $T_C = 25$ °C 350		mW
T _{stg}	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

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THERMAL DATA

R _{thj-amb} •	Thermal Resistance Junction-Ambient	Max	357.1	°C/W	
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Device mounted on a PCB area of 1 cm²

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

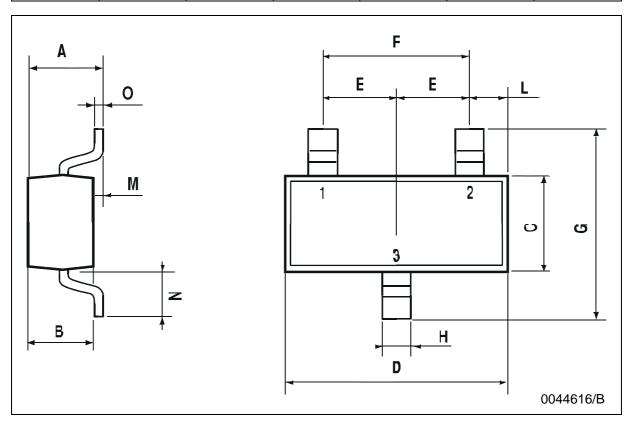
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CEX}	Collector Cut-off Current (V _{BE} = -3 V)	V _{CE} = -30 V			-50	nA
I _{BEX}	Base Cut-off Current (V _{BE} = -3 V)	V _{CE} = -30 V			-50	nA
I _{CBO}	Collector Cut-off Current (I _E = 0)	V _{CB} = -50 V			-10	nA
V _{(BR)CEO*}	Collector-Emitter Breakdown Voltage (I _B = 0)	I _C = -10 mA	-60			V
V _(BR) CBO	Collector-Base Breakdown Voltage (I _E = 0)	Ic = -10 μA	-60			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage (I _C = 0)	I _E = -10 μA	-5			V
$V_{CE(sat)^{*}}$	Collector-Emitter Saturation Voltage	$I_C = -150 \text{ mA}$ $I_B = -15 \text{ mA}$ $I_C = -500 \text{ mA}$ $I_B = -50 \text{ mA}$			-0.4 -1.6	V V
$V_{BE(sat)^*}$	Collector-Base Saturation Voltage	$I_C = -150 \text{ mA}$ $I_B = -15 \text{ mA}$ $I_C = -500 \text{ mA}$ $I_B = -50 \text{ mA}$			-1.3 -2.6	V V
h _{FE} *	DC Current Gain	$ \begin{array}{llllllllllllllllllllllllllllllllllll$	75 100 100 100 50		300	
f⊤	Transition Frequency	$I_C = -50 \text{ mA } V_{CE} = -20V f = 100MHz$	200			MHz
C_{CBO}	Collector-Base Capacitance	$I_E = 0$ $V_{CB} = -10 \text{ V}$ $f = 1 \text{ MHz}$			8	pF
C _{EBO}	Emitter-Base Capacitance	$I_C = 0$ $V_{EB} = -2 V$ $f = 1 MHz$			30	pF
t _d	Delay Time	I _C = -150 mA I _B = -15 mA			10	ns
t _r	Rise Time	V _{CC} = -30V			40	ns
t _{on}	Switching On Time				45	ns
ts	Storage Time	$I_C = -150 \text{ mA}$ $I_{B1} = -I_{B2} = -15 \text{mA}$		190		ns
t _f	Fall Time	$V_{CC} = -30V$			30	ns
t_{off}	Switching Off Time			220		ns

^{*} Pulsed: Pulse duration = 300 μs, duty cycle ≤ 2 %

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SOT-23 MECHANICAL DATA

DIM.	mm			mils		
Divis	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	0.85		1.1	33.4		43.3
В	0.65		0.95	25.6		37.4
С	1.20		1.4	47.2		55.1
D	2.80		3	110.2		118
Е	0.95		1.05	37.4		41.3
F	1.9		2.05	74.8		80.7
G	2.1		2.5	82.6		98.4
Н	0.38		0.48	14.9		18.8
L	0.3		0.6	11.8		23.6
М	0		0.1	0		3.9
N	0.3		0.65	11.8		25.6
0	0.09		0.17	3.5		6.7



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